

General Description

- Trench Power MOSFET - AlphaSGT™ technology
- Combined of low $R_{DS(ON)}$ and wide safe operating area (SOA)
- Higher in-rush current enabled for faster start-up and shorter down time
- RoHS and Halogen-Free Compliant

Applications

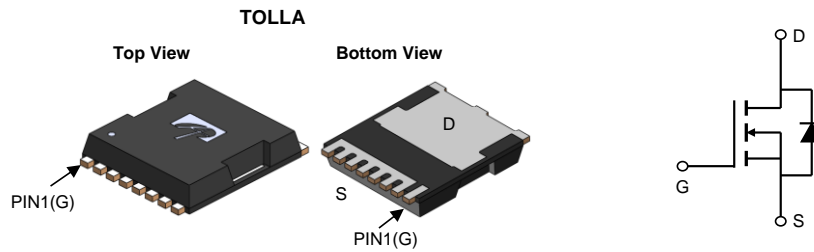
- Load switch
- BMS
- Motor

Product Summary

V_{DS}	150V
I_D (at $V_{GS}=10V$)	214A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	< 4.3m Ω
$R_{DS(ON)}$ (at $V_{GS}=8V$)	< 5m Ω

100% UIS Tested
 100% Rg Tested

Max $T_j=175^{\circ}C$



Orderable Part Number	Package Type	Form	Minimum Order Quantity
AOTL66518	TOLLA	Tape & Reel	2000

Absolute Maximum Ratings $T_A=25^{\circ}C$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DS}	150	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	214	A
Current		150	
Pulsed Drain Current ^C ($\leq 100\mu s$)	I_{DM}	710	
Continuous Drain Current	I_{DSM}	30	A
Current		25	
Avalanche Current ^C	I_{AS}	70	A
Avalanche energy $L=0.3mH$ ^C	E_{AS}	735	mJ
Diode reverse recovery	di/dt	500	A/us
$V_{DS}=0$ to 75V, $I_F \leq 300A$, $T_J \leq 125^{\circ}C$			
Power Dissipation ^B	P_D	500	W
		250	
Power Dissipation ^A	P_{DSM}	10	W
		7	
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 175	$^{\circ}C$

Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient ^A	$R_{\theta JA}$	10	15	$^{\circ}C/W$
Maximum Junction-to-Ambient ^{A,D}		35	45	$^{\circ}C/W$
Maximum Junction-to-Case	$R_{\theta JC}$	0.2	0.3	$^{\circ}C/W$

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
STATIC PARAMETERS						
BV _{DSS}	Drain-Source Breakdown Voltage	I _D =250μA, V _{GS} =0V	150			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =150V, V _{GS} =0V T _J =55°C			1 5	μA
I _{GSS}	Gate-Body leakage current	V _{DS} =0V, V _{GS} =±20V			±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	2.7	3.2	3.7	V
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =10V, I _D =20A T _J =125°C		3.5	4.3	mΩ
		V _{GS} =8V, I _D =20A		6.8	8.3	
g _{FS}	Forward Transconductance	V _{DS} =5V, I _D =20A		50		S
V _{SD}	Diode Forward Voltage	I _S =1A, V _{GS} =0V		0.68	1	V
I _S	Maximum Body-Diode Continuous Current				214	A
DYNAMIC PARAMETERS						
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =75V, f=1MHz		6460		pF
C _{oss}	Output Capacitance			820		pF
C _{rfs}	Reverse Transfer Capacitance			5		pF
R _g	Gate resistance	f=1MHz	1.1	2.3	3.5	Ω
SWITCHING PARAMETERS						
Q _{g(10V)}	Total Gate Charge	V _{GS} =10V, V _{DS} =75V, I _D =20A		80	115	nC
Q _{gs}	Gate Source Charge			32		nC
Q _{gd}	Gate Drain Charge			15		nC
Q _{oss}	Output Charge	V _{GS} =0V, V _{DS} =75V		273		nC
t _{D(on)}	Turn-On Delay Time	V _{GS} =10V, V _{DS} =75V, R _L =3.75Ω, R _{GEN} =3Ω		27		ns
t _r	Turn-On Rise Time			20		ns
t _{D(off)}	Turn-Off Delay Time			49		ns
t _f	Turn-Off Fall Time			28		ns
t _{rr}	Body Diode Reverse Recovery Time	I _F =20A, di/dt=500A/μs		86		ns
Q _{rr}	Body Diode Reverse Recovery Charge	I _F =20A, di/dt=500A/μs		920		nC

A. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25° C. The Power dissipation P_{DSM} is based on R_{θJA} ≤ 10s and the maximum allowed junction temperature of 175° C. The value in any given application depends on the user's specific board design, and the maximum temperature of 175° C may be used if the PCB allows it.

B. The power dissipation P_D is based on T_{J(MAX)}=175° C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.

C. Single pulse width limited by junction temperature T_{J(MAX)}=175° C.

D. The R_{θJA} is the sum of the thermal impedance from junction to case R_{θJC} and case to ambient.

E. The static characteristics in Figures 1 to 6 are obtained using <300μs pulses, duty cycle 0.5% max.

F. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=175° C. The SOA curve provides a single pulse rating.

G. The maximum current rating is package limited.

H. These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25° C.

APPLICATIONS OR USES AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS ARE NOT AUTHORIZED. AOS DOES NOT ASSUME ANY LIABILITY ARISING OUT OF SUCH APPLICATIONS OR USES OF ITS PRODUCTS. AOS RESERVES THE RIGHT TO MAKE CHANGES TO PRODUCT SPECIFICATIONS WITHOUT NOTICE. IT IS THE RESPONSIBILITY OF THE CUSTOMER TO EVALUATE SUITABILITY OF THE PRODUCT FOR THEIR INTENDED APPLICATION. CUSTOMER SHALL COMPLY WITH APPLICABLE LEGAL REQUIREMENTS, INCLUDING ALL APPLICABLE EXPORT CONTROL RULES, REGULATIONS AND LIMITATIONS.

AOS' products are provided subject to AOS' terms and conditions of sale which are set forth at:

http://www.aosmd.com/terms_and_conditions_of_sale

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

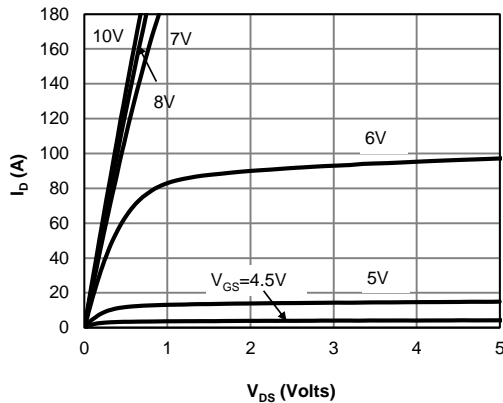


Figure 1: On-Region Characteristics (Note E)

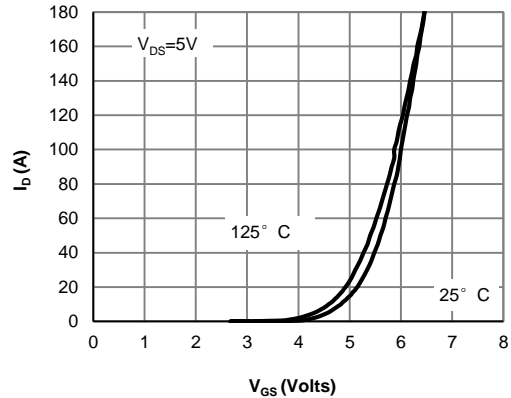


Figure 2: Transfer Characteristics (Note E)

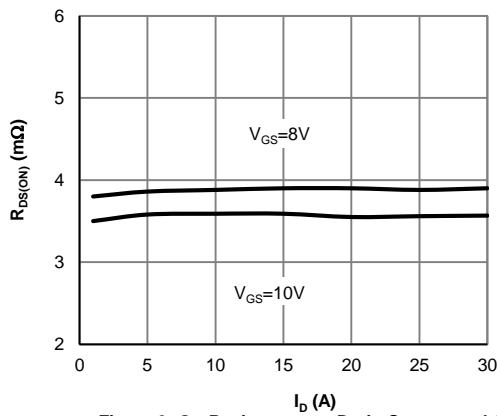


Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

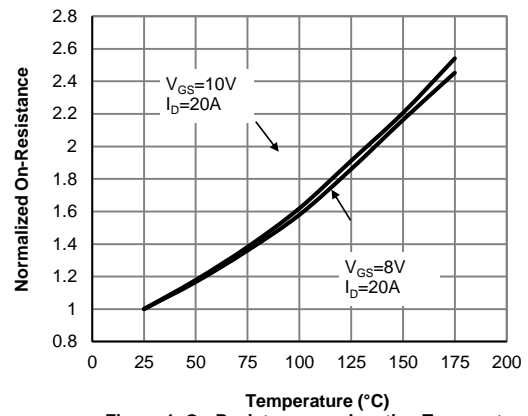


Figure 4: On-Resistance vs. Junction Temperature (Note E)

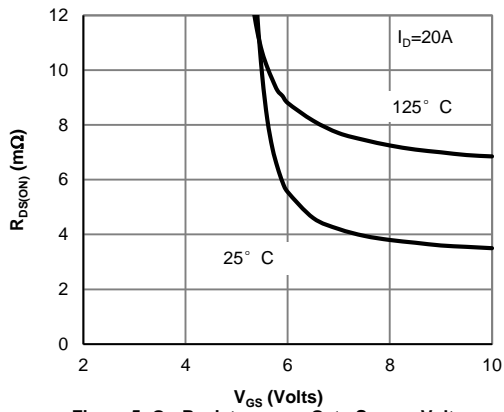


Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

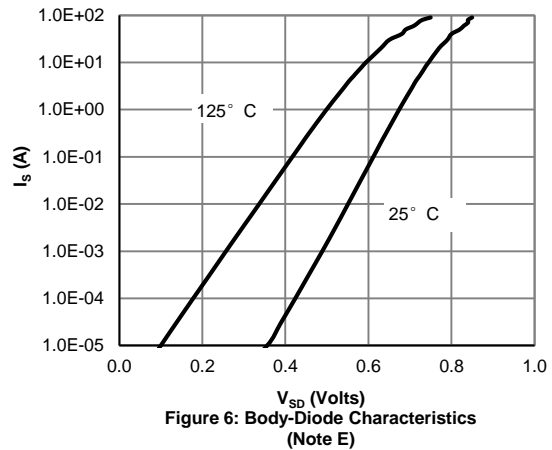


Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

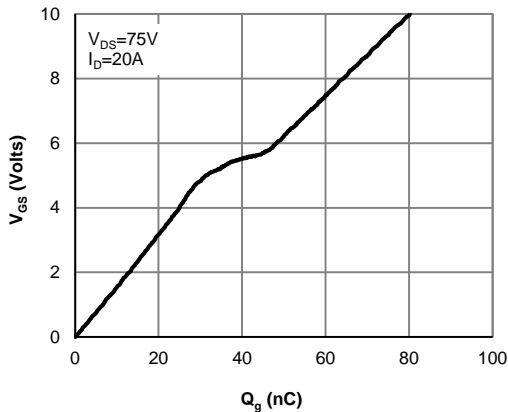


Figure 7: Gate-Charge Characteristics

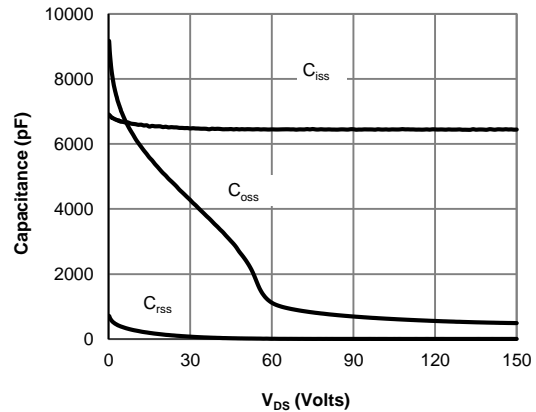


Figure 8: Capacitance Characteristics

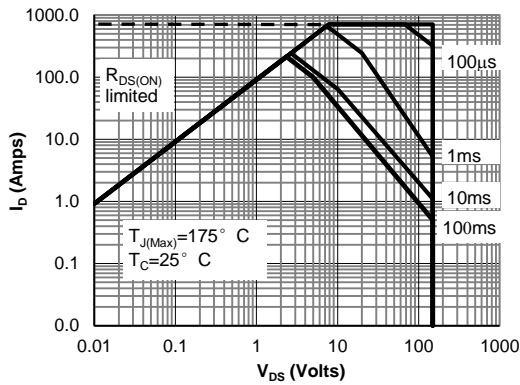


Figure 9: Maximum Forward Biased Safe Operating Area (Note F)

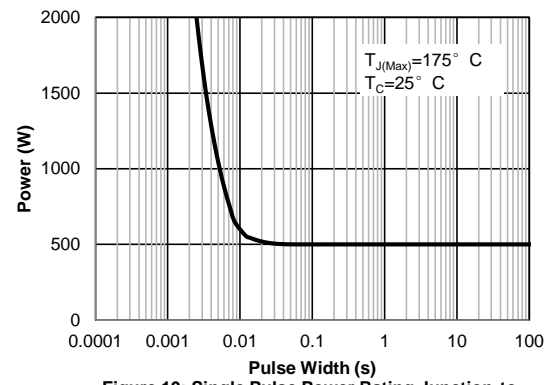


Figure 10: Single Pulse Power Rating Junction-to-Case (Note F)

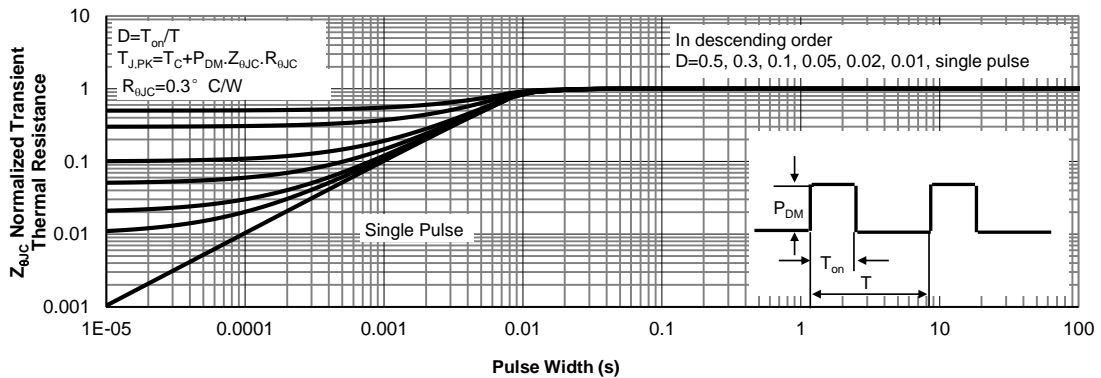


Figure 11: Normalized Maximum Transient Thermal Impedance (Note F)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

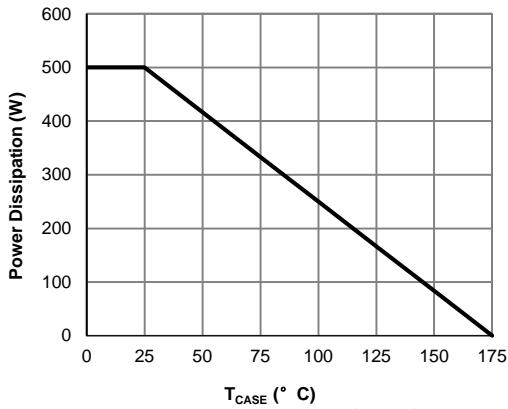


Figure 12: Power De-rating (Note F)

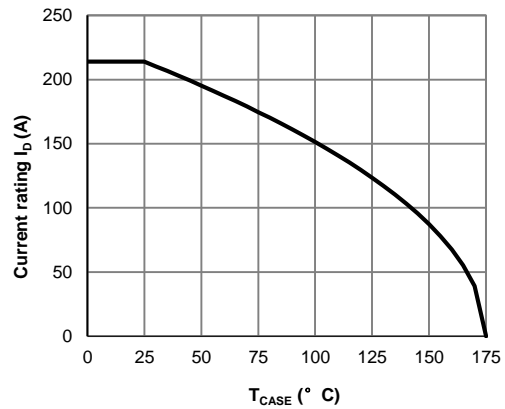


Figure 13: Current De-rating (Note F)

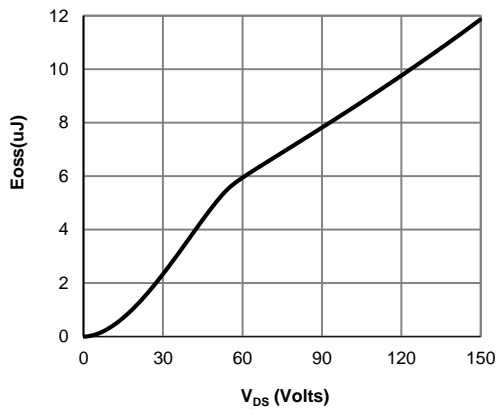


Figure 14: Coss stored Energy

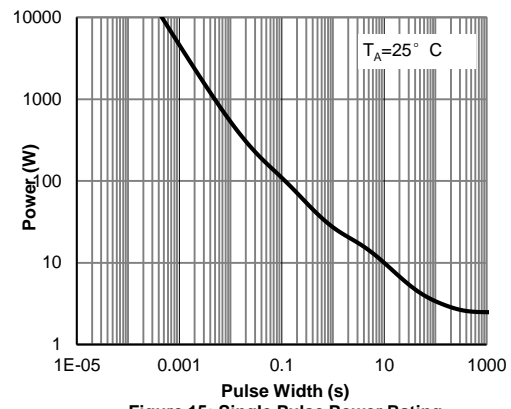


Figure 15: Single Pulse Power Rating Junction-to-Ambient (Note H)

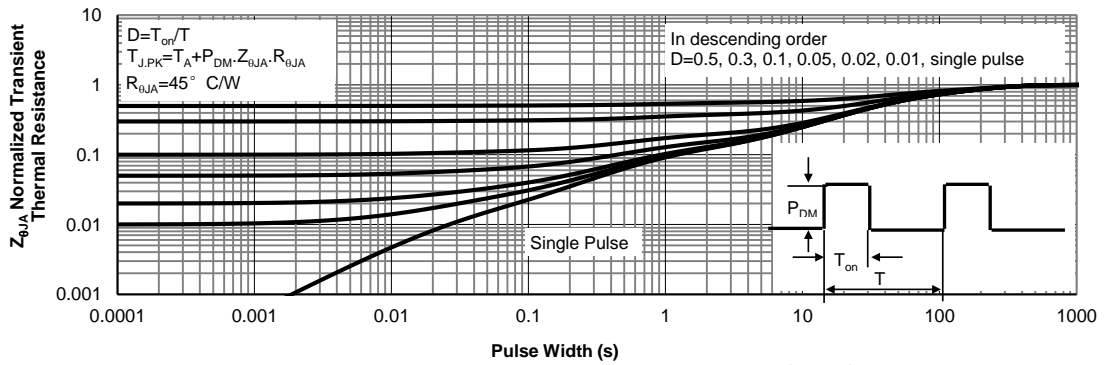


Figure 16: Normalized Maximum Transient Thermal Impedance (Note H)

Figure A: Gate Charge Test Circuit & Waveforms

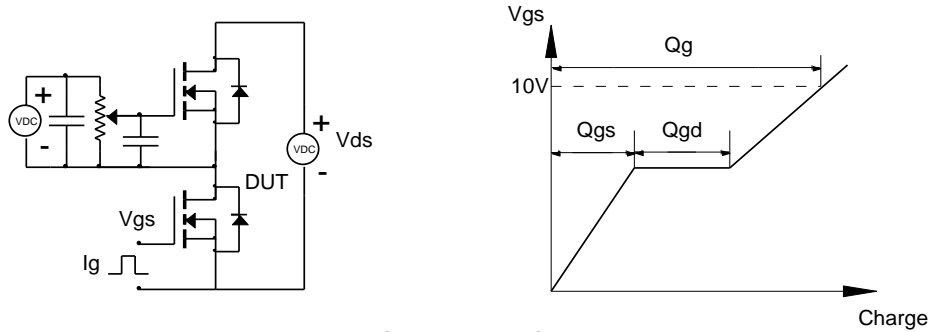


Figure B: Resistive Switching Test Circuit & Waveforms

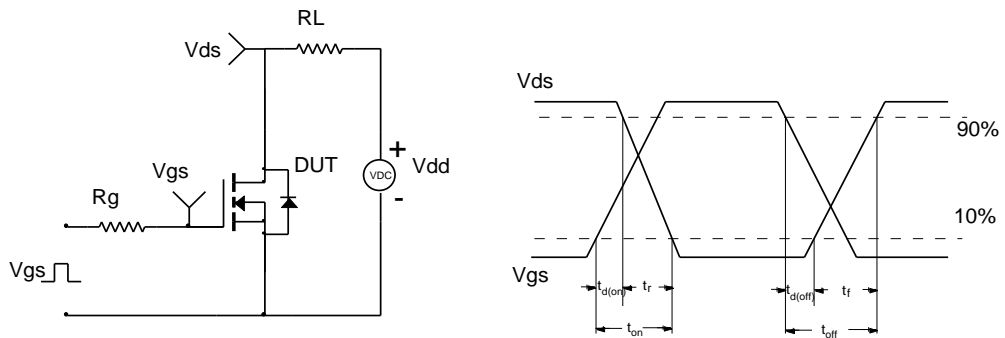


Figure C: Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

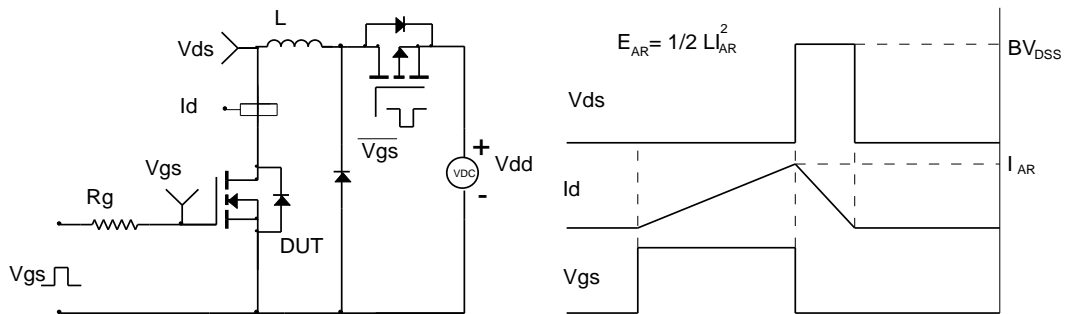
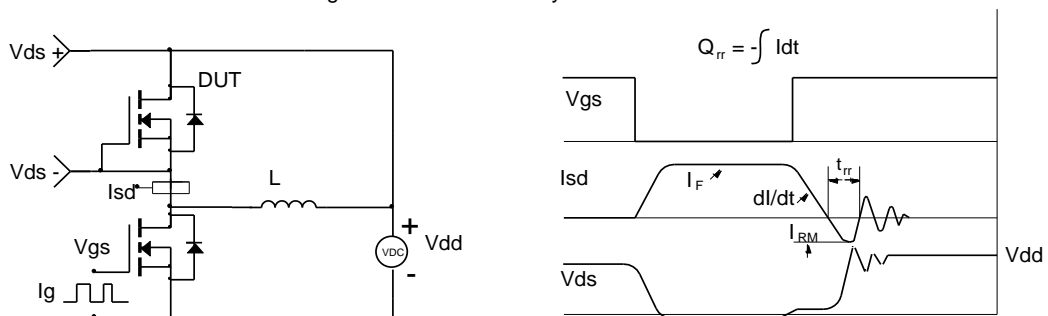


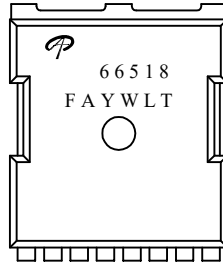
Figure D: Diode Recovery Test Circuit & Waveforms





Document No.	PD-03152
Version	B
Title	AOTL66518 Marking Description

TOLLA PACKAGE MARKING DESCRIPTION



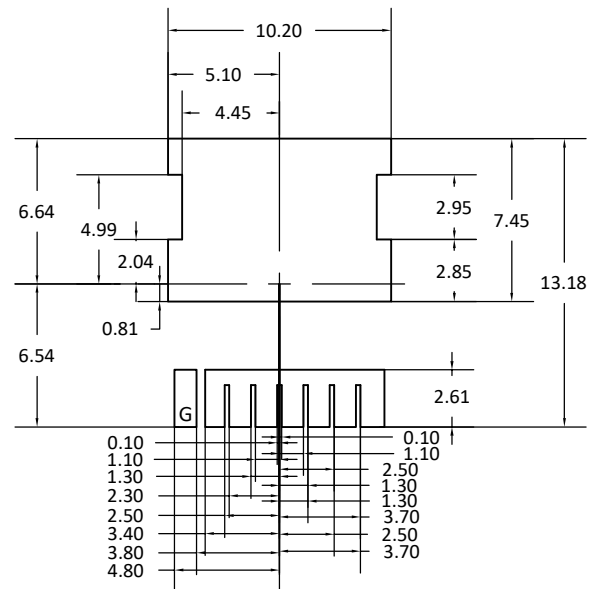
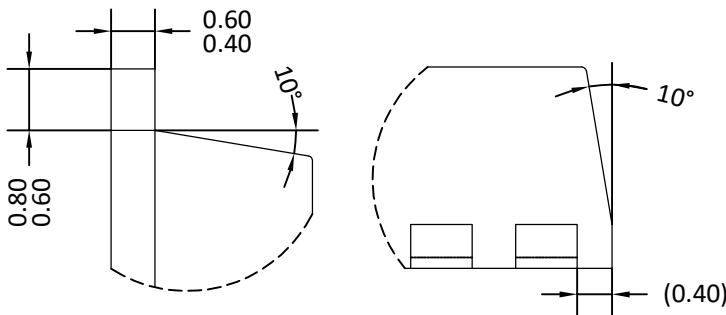
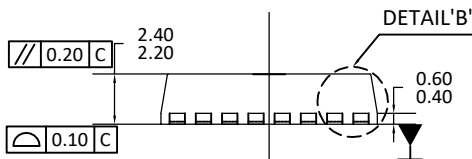
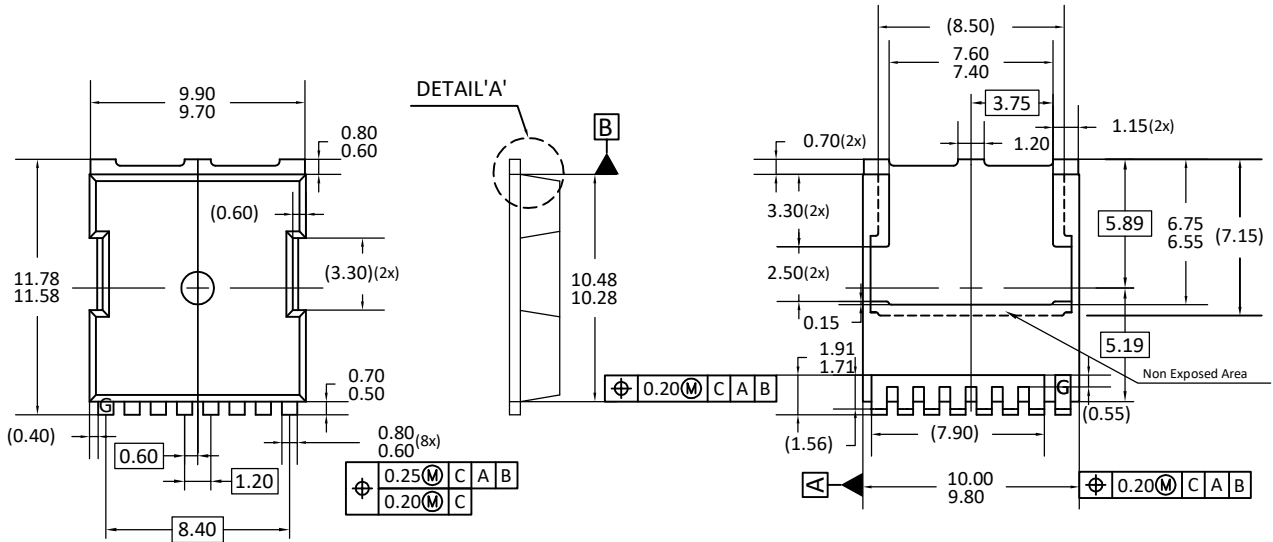
Green product

NOTE:	
LOGO	- AOS Logo
66518	- Part number code
F	- Fab code
A	- Assembly location code
Y	- Year code
W	- Week code
L&T	- Assembly lot code

PART NO.	DESCRIPTION	CODE
AOTL66518	Green product	66518



TOLLA PACKAGE OUTLINE



UNIT: mm

NOTE:

- A) PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH SHOULD BE LESS THAN 6 MIL.
- B) TOLERANCE 0.100 MILLIMETERS UNLESS OTHERWISE SPECIFIED.
- C) CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.
- D) () IS REFERENCE.
- E) THIS PACKAGE WAS QUALIFIED USING IR REFLOW PROCESS (JEDEC STANDARD). FOR USAGE IN OTHER SOLDERING PROCESSES, PLEASE CONTACT LOCAL AOS REPRESENTATIVES.

LAND PATTERN RECOMMENDATIONS



Alpha & Omega Semiconductor Product Reliability Report

AOTL66518, rev A

Plastic Encapsulated Device

ALPHA & OMEGA Semiconductor, Inc

www.aosmd.com

Jun, 2020

This AOS product reliability report summarizes the qualification result for AOTL66518. Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AOTL66518 passes AOS quality and reliability requirements. The released product will be categorized by the process family and be routine monitored for continuously improving the product quality.

I. Reliability Stress Test Summary and Results

Test Item	Test Condition	Time Point	Total Sample Size	Number of Failures	Reference Standard
HTGB	Temp = 175°C , Vgs=100% of Vgsmax	168 / 500 / 1000 hours	231 pcs	0	JESD22-A108
HTRB	Temp = 175°C , Vds=100% of Vdsmax	168 / 500 / 1000 hours	231 pcs	0	JESD22-A108
Precondition (Note A)	168hr 85°C / 85%RH + 3 cycle reflow@260°C (MSL 1)	-	693 pcs	0	JESD22-A113
HAST	130°C , 85%RH, 33.3 psia, Vds = 80% of Vdsmax up to 42V	96 hours	231 pcs	0	JESD22-A110
Autoclave	121°C , 29.7psia, RH=100%	96 hours	231 pcs	0	JESD22-A102
Temperature Cycle	-55°C to 150°C , air to air,	1000 cycles	231 pcs	0	JESD22-A104

Note: The reliability data presents total of available generic data up to the published date.

Note A: MSL (Moisture Sensitivity Level) 1 based on J-STD-020

II. Reliability Evaluation

FIT rate (per billion): 2.61

MTTF = 43670 years

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

Failure Rate = $\text{Chi}^2 \times 10^9 / [2 (N) (H) (Af)] = 2.61$

MTTF = $10^9 / \text{FIT} = 43670 \text{ years}$

Chi² = Chi Squared Distribution, determined by the number of failures and confidence interval

N = Total Number of units from burn-in tests

H = Duration of burn-in testing

Af = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and Tuse = 55°C)

Acceleration Factor [**Af**] = $\text{Exp} [Ea / k (1/Tj u - 1/Tj s)]$

Acceleration Factor ratio list:

	55 deg C	70 deg C	85 deg C	100 deg C	125 deg C	150 deg C	175 deg C
Af	758	256	95	38	9.7	2.9	1

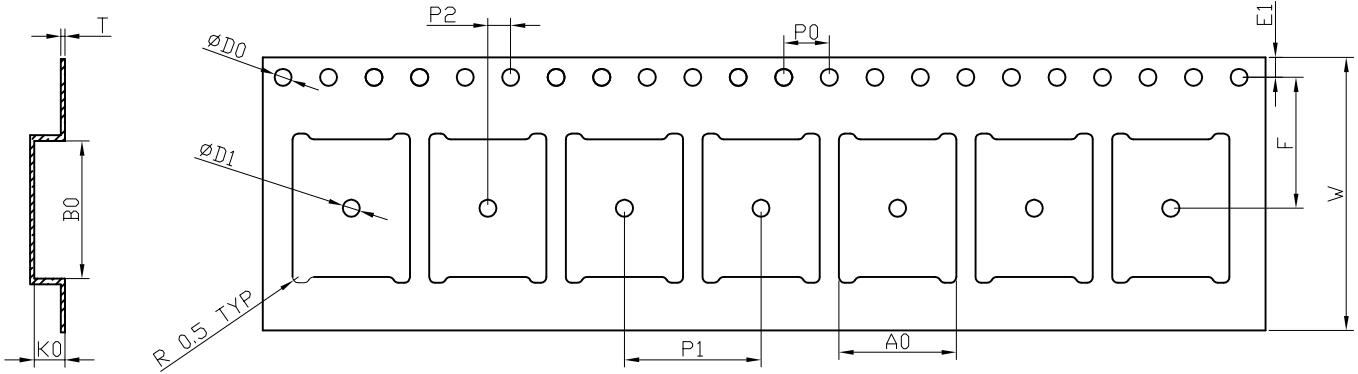
Tj s = Stressed junction temperature in degree (Kelvin), K = C+273.16

Tj u = The use junction temperature in degree (Kelvin), K = C+273.16

k = Boltzmann's constant, $8.617164 \times 10^{-5} \text{eV} / \text{K}$



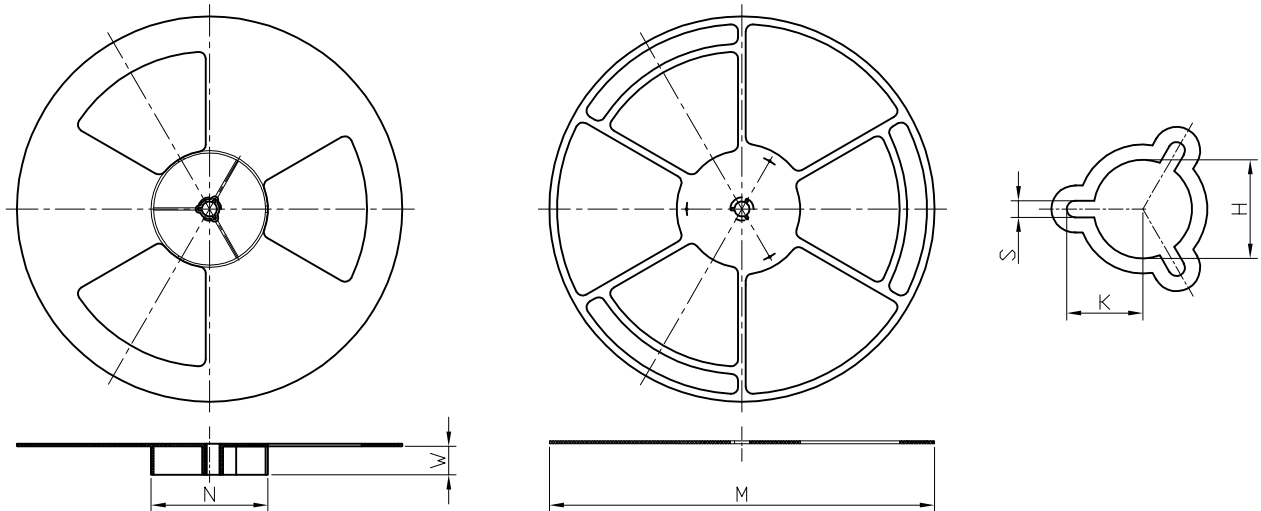
TOLL Carrier Tape



UNIT: MM

PACKAGE	A0	B0	K0	D0	D1	W	E1	F	P0	P1	P2	T
TOLL (24 MM)	10.30 ±0.10	12.10 ±0.10	2.60 ±0.10	1.50 +0.10	1.50 MIN.	24.00 ±0.30	1.75 ±0.10	11.50 ±0.10	4.00 ±0.10	12.00 ±0.10	2.00 ±0.10	0.35 ±0.04

TOLL Reel



UNIT: MM

TAPE SIZE	REEL SIZE	M	N	W	H	K	S
24 mm	ø330	ø330.00 +0.25 -4.00	ø100.00 ±0.2	24.4 +2.0 -0.0	ø13.00 +0.50 -0.20	10.5 ±0.25	2.2 ±0.25

TOLL Tape

Leader / Trailer
& Orientation

Unit Per Reel:
2000pcs

